

Excellent Integrated System Limited

Stocking Distributor

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<u>Vishay Semiconductor/Diodes Division</u> <u>MURB820</u>

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Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of MURB820 - DIODE GEN PURP 200V 8A D2PAK

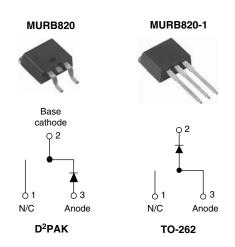
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MURB820/MURB820-1

Vishay High Power Products

Ultrafast Rectifier, 8 A FRED PtTM



PRODUCT SUMMARY				
t _{rr} 25 ns				
I _{F(AV)}	8 A			
V _R	200 V			

FEATURES

- · Ultrafast recovery time
- Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature
- · Designed and qualified for industrial level

DESCRIPTION/APPLICATIONS

MUR.. series are the state of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, dc-to-dc converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Peak repetitive reverse voltage	V_{RRM}		200	V	
Average rectified forward current	I _{F(AV)}	Total device, rated V _R , T _C = 150 °C	8		
Non-repetitive peak surge current	I _{FSM}		100	Α	
Peak repetitive forward current	I _{FM}	Rated V _R , square wave, 20 kHz, T _C = 150 °C	16		
Operating junction and storage temperatures	T _J , T _{Stg}		- 65 to 175	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	200	-	-	
Forward voltage V _F		I _F = 8 A	-	-	0.975	V
Forward voltage V _F	I _F = 8 A, T _J = 150 °C	-	-	0.895		
Reverse leakage current I _R		$V_R = V_R$ rated	-	-	5	
		T _J = 150 °C, V _R = V _R rated	-	-	250	μΑ
Junction capacitance	C _T	V _R = 200 V	-	25	-	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH

Document Number: 93123 Revision: 24-Jun-08



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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	-	35		
Reverse recovery time t _{rr}		I _F = 0.5 A, I _R = 1.0 A, I _{REC} = 0.25 A		-	-	25		
	^L rr	T _J = 25 °C	$I_F = 8 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_B = 160 \text{ V}$	-	20	-	ns	
		T _J = 125 °C		-	34	-		
Peak recovery current I _{RRM}	I _{RRM}	T _J = 25 °C		-	1.7	-	Α	
		T _J = 125 °C		-	4.2	-	_ A	
Reverse recovery charge	Q _{rr}		T _J = 25 °C	·n	-	23	-	nC
		T _J = 125 °C		-	75	-	nc nc	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65	-	175	°C	
Thermal resistance, junction to case	R _{thJC}		-	-	3.0		
Thermal resistance, junction to ambient	R _{thJA}		-	-	50	°C/W	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-		
Weight			-	2.0	-	g	
			-	0.07	-	OZ.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf ⋅ cm (lbf ⋅ in)	
Mayling daying		Case style D ² PAK	MURB820				
Marking device		Case style TO-262	MURB820-1				



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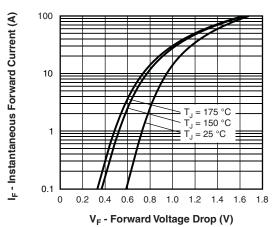


Fig. 1 - Typical Forward Voltage Drop Characteristics

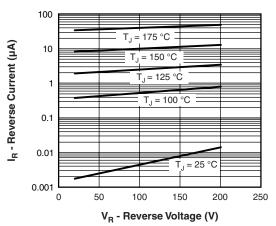


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

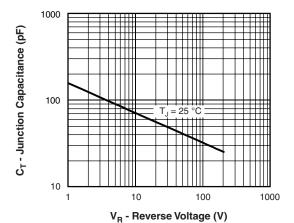


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

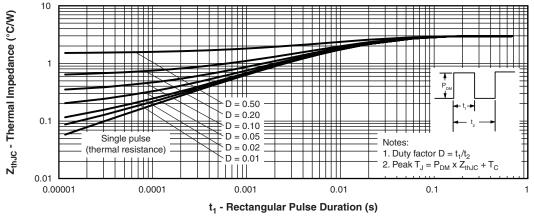


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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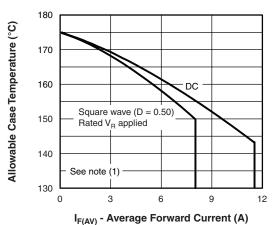


Fig. 5 - Maximum Allowable Case Temperature vs.

Average Forward Current

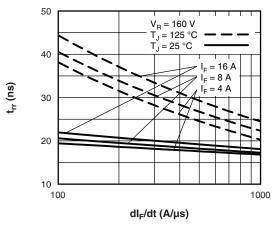


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

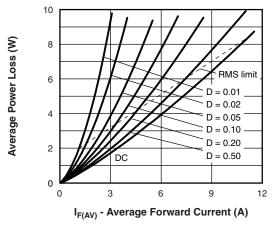


Fig. 6 - Forward Power Loss Characteristics

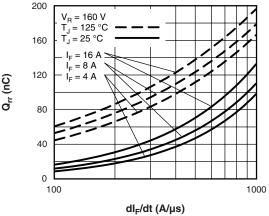


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

 $\begin{array}{l} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \ x \ R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \ x \ V_{FM} \ \text{at } (I_{F(AV)}/D) \ \text{(see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \ x \ I_R \ (1 - D); \ I_R \ \text{at } V_{R1} = \text{Rated } V_R \\ \end{array}$



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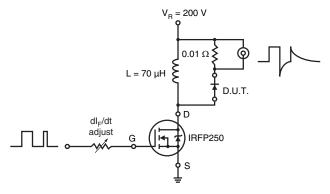
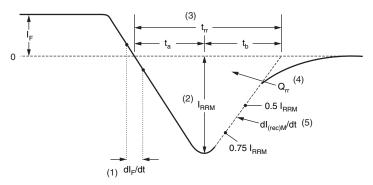


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dI_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions



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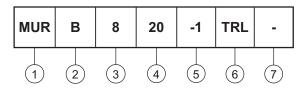
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ORDERING INFORMATION TABLE

Device code



- 1 Ultrafast MUR series
- B = D²PAK/TO-262
- **3** Current rating (8 = 8 A)
- Voltage rating (20 = 200 V)
- None = D²PAK
 - • -1 = TO-262
- None = Tube (50 pieces)
 - TRL = Tape and reel (left oriented, for D²PAK package)
 - TRR = Tape and reel (right oriented, for D²PAK package)
- 7 • None = Standard production
 - PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95014				
Part marking information	http://www.vishay.com/doc?95008			
Packaging information	http://www.vishay.com/doc?95032			



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